NPN Epitaxial Planar Silicon Transistor

2SC4405



UHF, Low-Noise, **Wide-Band Amplifier Applications**

Applications

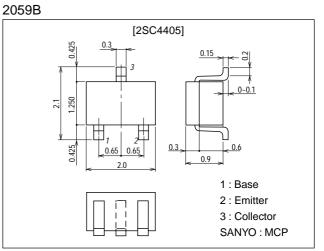
· UHF, low-noise amplifiers, wide-band amplifiers.

Features

- · High cutoff frequency : $f_T=5.0$ GHz typ
- · High power gain : MAG=14dB typ (f=0.9GHz)
- · Small noise figure : NF=1.5dB typ (f=0.9GHz)
- · Very small-sized package permitting 2SC4405-
- applied sets to be made smaller and slimmer.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

-				
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		20	V
Collector-to-Emitter Voltage	VCEO		12	V
Emitter-to-Base Voltage	VEBO		3	V
Collector Current	ι _C		100	mA
Collector Dissipation	PC		150	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Unit
Falameter	Symbol	min typ max	Onit
Collector Cutoff Current	ICBO	V _{CB} =12V, I _E =0 1.0	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =2V, I _C =0 10	μA
DC Current Gain	hFE	V _{CE} =10V, I _C =20mA 40* 200*	
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =20mA 5.0	GHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz 0.9 1.5	pF
Reverse Transfer Capacitance	Cre	V _{CB} =10V, f=1MHz 0.6	pF
* : The 2SC4405 is classified by 20mA h _{FE} as fo	llows : 40	2 80 60 3 120 100 4 200	

(Note) Marking : OY

h_{FE} rank : 2, 3, 4

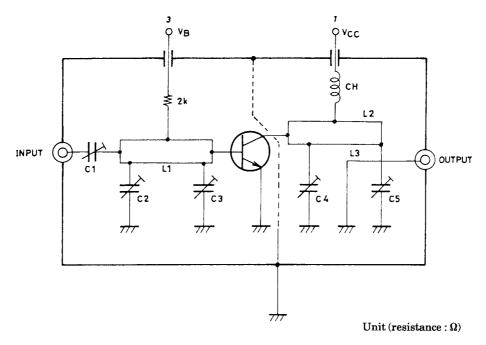
• For CP package version, use the 2SC3775.

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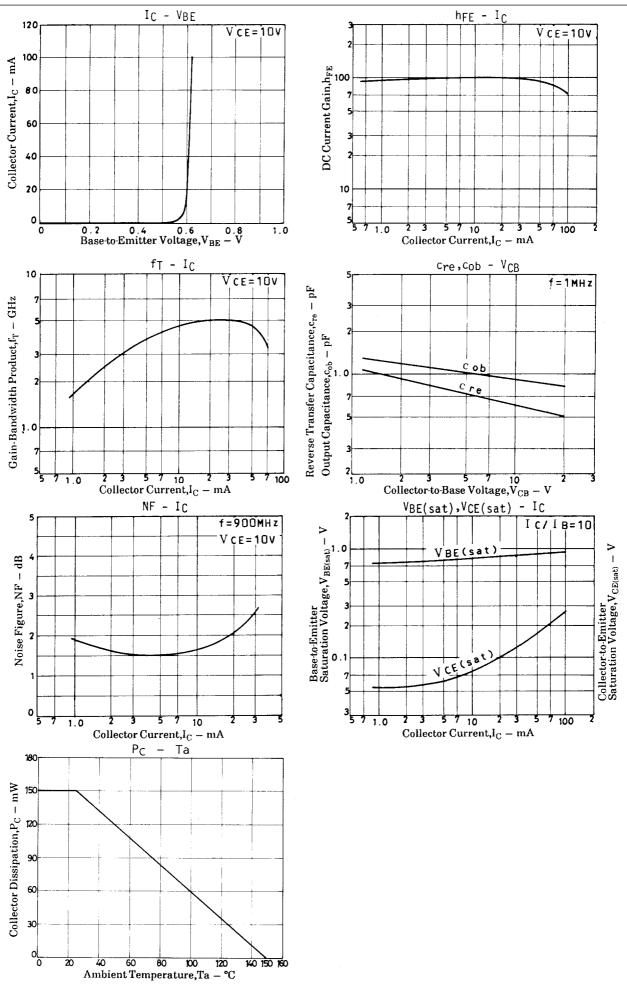
SANYO Electric Co., Ltd. Semiconductor Bussiness Headquaters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

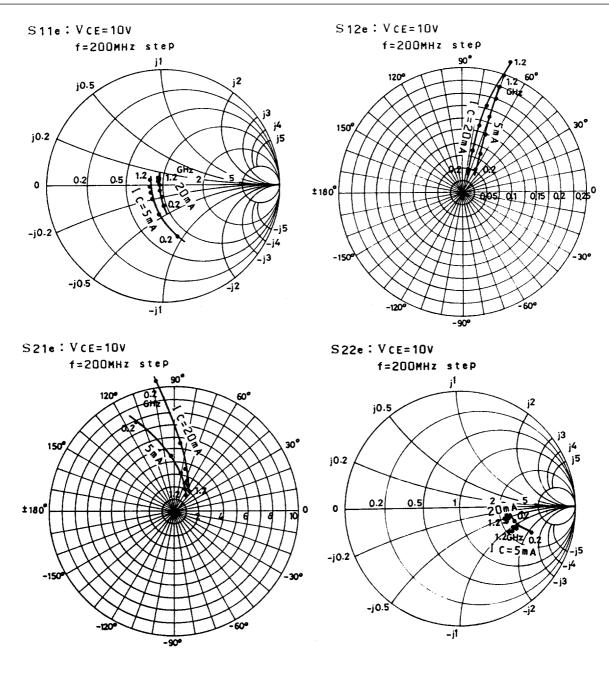
Parameter	Symbol	Conditions	Ratings		Unit	
			min	typ	max	Onit
Forward Transfer Gain	S21e ²	V _{CE} =10V, I _C =20mA, f=0.9GHz	8.5	10		dB
Maximum Available Power Gain	MAG	V _{CE} =10V, I _C =20mA, f=0.9GHz		14		dB
Noise Figure	NF	V _{CE} =10V, I _C =5mA, f=0.9GHz See specified Test Circuit.		1.5		dB

NF Test Circuit



	900MHz
C1	~5pF
C2	~10pF
C3	~10pF
C4	~10pF
C5	~10pF
L1	W ≈ 1.5mm, I ≈ 25mm
	Strip line
L2	W ≈ 4mm, I ≈ 25mm
	Strip line
L3	0.5¢, I ≈ 40mm
СН	2t+bead core





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